Renesas Electronics America Inc - R5F212BCSNLG#U0 Datasheet

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	R8C
Core Size	16-Bit
Speed	20MHz
Connectivity	I²C, LINbus, SIO, SSU, UART/USART
Peripherals	POR, PWM, Voltage Detect, WDT
Number of I/O	55
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	7.5K x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 5.5V
Data Converters	A/D 12x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-20°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-TFLGA
Supplier Device Package	64-TFLGA (6x6)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f212bcsnlg-u0

1.1.2 Specifications

Tables 1.1 and 1.2 outlines the Specifications for R8C/2A Group and Tables 1.3 and 1.4 outlines the Specifications for R8C/2B Group.

Table 1.1 Specifications for R8C/2A Group (1)

Item	Function	Specification
CPU	Central processing unit	R8C/Tiny series core • Number of fundamental instructions: 89 • Minimum instruction execution time: 50 ns (f(XIN) = 20 MHz, VCC = 3.0 to 5.5 V) 100 ns (f(XIN) = 10 MHz, VCC = 2.7 to 5.5 V) 200 ns (f(XIN) = 5 MHz, VCC = 2.2 to 5.5 V) • Multiplier: 16 bits × 16 bits → 32 bits • Multiply-accumulate instruction: 16 bits × 16 bits + 32 bits → 32 bits • Operation mode: Single-chip mode (address space: 1 Mbyte)
Memory	ROM, RAM	Refer to **Table 1.5 Product List for R8C/2A Group**.
Power Supply Voltage Detection	Voltage detection circuit	• Power-on reset • Voltage detection 2
I/O Ports	Programmable I/O ports	• Input-only: 2 pins • CMOS I/O ports: 55, selectable pull-up resistor • High current drive ports: 8
Clock	Clock generation circuits	3 circuits: XIN clock oscillation circuit (with on-chip feedback resistor), On-chip oscillator (high-speed, low-speed) (high-speed on-chip oscillator has a frequency adjustment function), XCIN clock oscillation circuit (32 kHz) • Oscillation stop detection: XIN clock oscillation stop detection function • Frequency divider circuit: Dividing selectable 1, 2, 4, 8, and 16 • Low power consumption modes: Standard operating mode (high-speed clock, low-speed clock, high-speed on-chip oscillator, low-speed on-chip oscillator), wait mode, stop mode
		Real-time clock (timer RE)
Interrupts		• External: 5 sources, Internal: 23 sources, Software: 4 sources • Priority levels: 7 levels
Watchdog Timer		15 bits × 1 (with prescaler), reset start selectable
Timer	Timer RA	8 bits × 1 (with 8-bit prescaler) Timer mode (period timer), pulse output mode (output level inverted every period), event counter mode, pulse width measurement mode, pulse period measurement mode
	Timer RB	8 bits × 1 (with 8-bit prescaler) Timer mode (period timer), programmable waveform generation mode (PWM output), programmable one-shot generation mode, programmable wait one-shot generation mode
	Timer RC	16 bits × 1 (with 4 capture/compare registers) Timer mode (input capture function, output compare function), PWM mode (output 3 pins), PWM2 mode (PWM output pin)
	Timer RD	16 bits × 2 (with 4 capture/compare registers) Timer mode (input capture function, output compare function), PWM mode (output 6 pins), reset synchronous PWM mode (output three-phase waveforms (6 pins), sawtooth wave modulation), complementary PWM mode (output three-phase waveforms (6 pins), triangular wave modulation), PWM3 mode (PWM output 2 pins with fixed period)
	Timer RE	8 bits × 1 Real-time clock mode (count seconds, minutes, hours, days of week), output compare mode
	Timer RF	16 bits × 1 (with capture/compare register pin and compare register pin) Input capture mode, output compare mode

Table 1.6 Product List for R8C/2B Group **Current of Nov. 2007**

Part No.	ROM Capacity		RAM Capacity	Package Type	Remarks	
	Program ROM	Data flash				
R5F212B7SNFP	48 Kbytes	1 Kbyte × 2	2.5 Kbytes	PLQP0064KB-A	N version	
R5F212B7SNFA	48 Kbytes	1 Kbyte × 2	2.5 Kbytes	PLQP0064GA-A		
R5F212B7SNLG	48 Kbytes	1 Kbyte × 2	2.5 Kbytes	PTLG0064JA-A		
R5F212B8SNFP	64 Kbytes	1 Kbyte × 2	3 Kbytes	PLQP0064KB-A		
R5F212B8SNFA	64 Kbytes	1 Kbyte × 2	3 Kbytes	PLQP0064GA-A		
R5F212B8SNLG	64 Kbytes	1 Kbyte × 2	3 Kbytes	PTLG0064JA-A		
R5F212BASNFP	96 Kbytes	1 Kbyte × 2	7 Kbytes	PLQP0064KB-A		
R5F212BASNFA	96 Kbytes	1 Kbyte × 2	7 Kbytes	PLQP0064GA-A		
R5F212BASNLG	96 Kbytes	1 Kbyte × 2	7 Kbytes	PTLG0064JA-A		
R5F212BCSNFP	128 Kbytes	1 Kbyte × 2	7.5 Kbytes	PLQP0064KB-A		
R5F212BCSNFA	128 Kbytes	1 Kbyte × 2	7.5 Kbytes	PLQP0064GA-A		
R5F212BCSNLG	128 Kbytes	1 Kbyte × 2	7.5 Kbytes	PTLG0064JA-A		
R5F212B7SDFP	48 Kbytes	1 Kbyte × 2	2.5 Kbytes	PLQP0064KB-A	D version	
R5F212B7SDFA	48 Kbytes	1 Kbyte × 2	2.5 Kbytes	PLQP0064GA-A		
R5F212B8SDFP	64 Kbytes	1 Kbyte × 2	3 Kbytes	PLQP0064KB-A		
R5F212B8SDFA	64 Kbytes	1 Kbyte × 2	3 Kbytes	PLQP0064GA-A		
R5F212BASDFP	96 Kbytes	1 Kbyte × 2	7 Kbytes	PLQP0064KB-A		
R5F212BASDFA	96 Kbytes	1 Kbyte × 2	7 Kbytes	PLQP0064GA-A		
R5F212BCSDFP	128 Kbytes	1 Kbyte × 2	7.5 Kbytes	PLQP0064KB-A		
R5F212BCSDFA	128 Kbytes	1 Kbyte × 2	7.5 Kbytes	PLQP0064GA-A		
R5F212B7SNXXXFP	48 Kbytes	1 Kbyte × 2	2.5 Kbytes	PLQP0064KB-A	N version	Factory programming product(1)
R5F212B7SNXXXFA	48 Kbytes	1 Kbyte × 2	2.5 Kbytes	PLQP0064GA-A		
R5F212B7SNXXXLG	48 Kbytes	1 Kbyte × 2	2.5 Kbytes	PTLG0064JA-A		
R5F212B8SNXXXFP	64 Kbytes	1 Kbyte × 2	3 Kbytes	PLQP0064KB-A		
R5F212B8SNXXXFA	64 Kbytes	1 Kbyte × 2	3 Kbytes	PLQP0064GA-A		
R5F212B8SNXXXLG	64 Kbytes	1 Kbyte × 2	3 Kbytes	PTLG0064JA-A		
R5F212BASNXXXFP	96 Kbytes	1 Kbyte × 2	7 Kbytes	PLQP0064KB-A		
R5F212BASNXXXFA	96 Kbytes	1 Kbyte × 2	7 Kbytes	PLQP0064GA-A		
R5F212BASNXXXLG	96 Kbytes	1 Kbyte × 2	7 Kbytes	PTLG0064JA-A		
R5F212BCSNXXXFP	128 Kbytes	1 Kbyte × 2	7.5 Kbytes	PLQP0064KB-A		
R5F212BCSNXXXFA	128 Kbytes	1 Kbyte × 2	7.5 Kbytes	PLQP0064GA-A		
R5F212BCSNXXXLG	128 Kbytes	1 Kbyte × 2	7.5 Kbytes	PTLG0064JA-A		
R5F212B7SDXXXFP	48 Kbytes	1 Kbyte × 2	2.5 Kbytes	PLQP0064KB-A	D version	
R5F212B7SDXXXFA	48 Kbytes	1 Kbyte × 2	2.5 Kbytes	PLQP0064GA-A		
R5F212B8SDXXXFP	64 Kbytes	1 Kbyte × 2	3 Kbytes	PLQP0064KB-A		
R5F212B8SDXXXFA	64 Kbytes	1 Kbyte × 2	3 Kbytes	PLQP0064GA-A		
R5F212BASDXXXFP	96 Kbytes	1 Kbyte × 2	7 Kbytes	PLQP0064KB-A		
R5F212BASDXXXFA	96 Kbytes	1 Kbyte × 2	7 Kbytes	PLQP0064GA-A		
R5F212BCSDXXXFP	128 Kbytes	1 Kbyte × 2	7.5 Kbytes	PLQP0064KB-A		
R5F212BCSDXXXFA	128 Kbytes	1 Kbyte × 2	7.5 Kbytes	PLQP0064GA-A		

NOTE:
1. The user ROM is programmed before shipment.

1.3 Block Diagram

Figure 1.3 shows a Block Diagram.

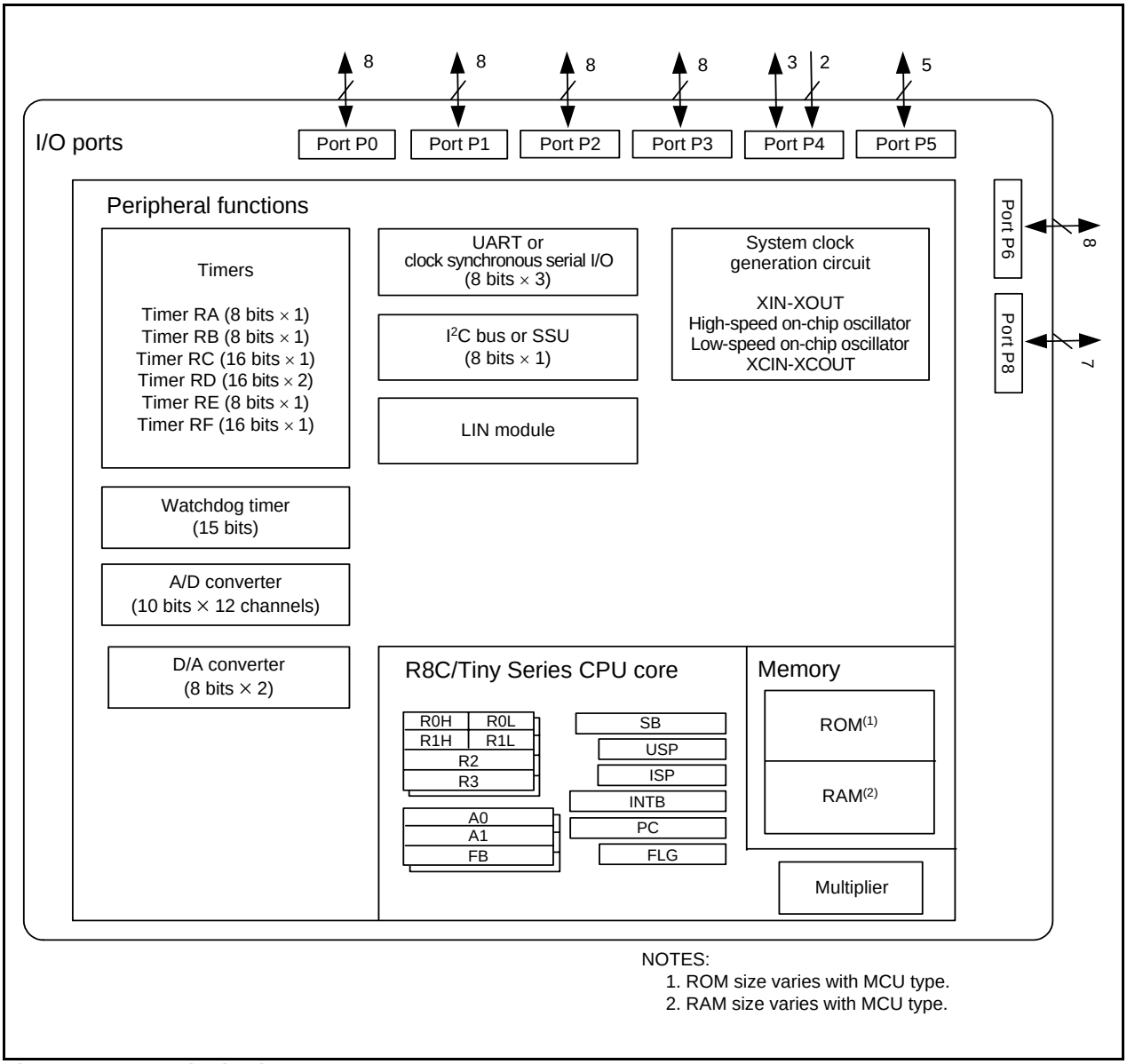


Figure 1.3 Block Diagram

Table 1.7 Pin Name Information by Pin Number (1)

Pin Number	Control Pin	Port	I/O Pin Functions for of Peripheral Modules					
			Interrupt	Timer	Serial Interface	SSU	I^2C bus	A/D Converter, D/A Converter
1		P3_3				SSI		
2		P3_4				SCS	SDA	
3	MODE							
4	XCIN	P4_3						
5	XCOUT	P4_4						
6	$\overline{\text{RESET}}$							
7	XOUT	P4_7						
8	VSS/AVSS							
9	XIN	P4_6						
10	VCC/AVCC							
11		P5_4		TRCIOD				
12		P5_3		TRCIOC				
13		P5_2		TRCIOB				
14		P5_1		TRCIOA/TRCTRG				
15		P5_0		TRCCLK				
16		P2_7		TRDIOD1				
17		P2_6		TRDIOC1				
18		P2_5		TRDIOB1				
19		P2_4		TRDIOA1				
20		P2_3		TRDIOD0				
21		P2_2		TRDIOC0				
22		P2_1		TRDIOB0				
23		P2_0		TRDIOA0/TRDCLK				
24		P1_7	$\overline{\text{INT1}}$	TRAIO				
25		P1_6			CLK0			
26		P1_5	($\overline{\text{INT1}}$)(1)	(TRAIO)(1)	RXD0			
27		P1_4			TXD0			
28		P8_6						
29		P8_5		TRFO12				
30		P8_4		TRFO11				
31		P8_3		TRFO10/TRFI				
32		P8_2		TRFO02				
33		P8_1		TRFO01				
34		P8_0		TRFO00				
35		P6_0		TREO				
36		P4_5	$\overline{\text{INT0}}$	$\overline{\text{INT0}}$				
37		P6_6	$\overline{\text{INT2}}$		TXD1			
38		P6_7	$\overline{\text{INT3}}$		RXD1			
39		P6_5			(CLK1)(1)/ CLK2			
40		P6_4			RXD2			
41		P6_3			TXD2			
42		P3_1		TRBO				
43		P3_0		TRAO				
44		P3_6	($\overline{\text{INT1}}$)(1)					
45		P3_2	($\overline{\text{INT2}}$)(1)					

NOTE:
1. Can be assigned to the pin in parentheses by a program.

Table 1.8 Pin Name Information by Pin Number (2)

Pin Number	Control Pin	Port	I/O Pin Functions for of Peripheral Modules					
			Interrupt	Timer	Serial Interface	SSU	I^2C bus	A/D Converter, D/A Converter
46		P1_3	$\overline{KI3}$					AN11
47		P1_2	$\overline{KI2}$					AN10
48		P1_1	$\overline{KI1}$					AN9
49		P1_0	$\overline{KI0}$					AN8
50		P0_0						AN7
51		P0_1						AN6
52		P0_2						AN5
53		P0_3						AN4
54		P0_4						AN3
55		P6_2						
56		P6_1						
57		P0_5			CLK1			AN2
58		P0_6						AN1/DA0
59	VSS/AVSS							
60		P0_7						AN0/DA1
61	VREF							
62	VCC/AVCC							
63		P3_7				SSO		
64		P3_5				SSCK	SCL	

2.8.7 Interrupt Enable Flag (I)

The I flag enables maskable interrupts.
Interrupt are disabled when the I flag is set to 0, and are enabled when the I flag is set to 1. The I flag is set to 0 when an interrupt request is acknowledged.

2.8.8 Stack Pointer Select Flag (U)

ISP is selected when the U flag is set to 0; USP is selected when the U flag is set to 1.
The U flag is set to 0 when a hardware interrupt request is acknowledged or the INT instruction of software interrupt numbers 0 to 31 is executed.

2.8.9 Processor Interrupt Priority Level (IPL)

IPL is 3 bits wide and assigns processor interrupt priority levels from level 0 to level 7.
If a requested interrupt has higher priority than IPL, the interrupt is enabled.

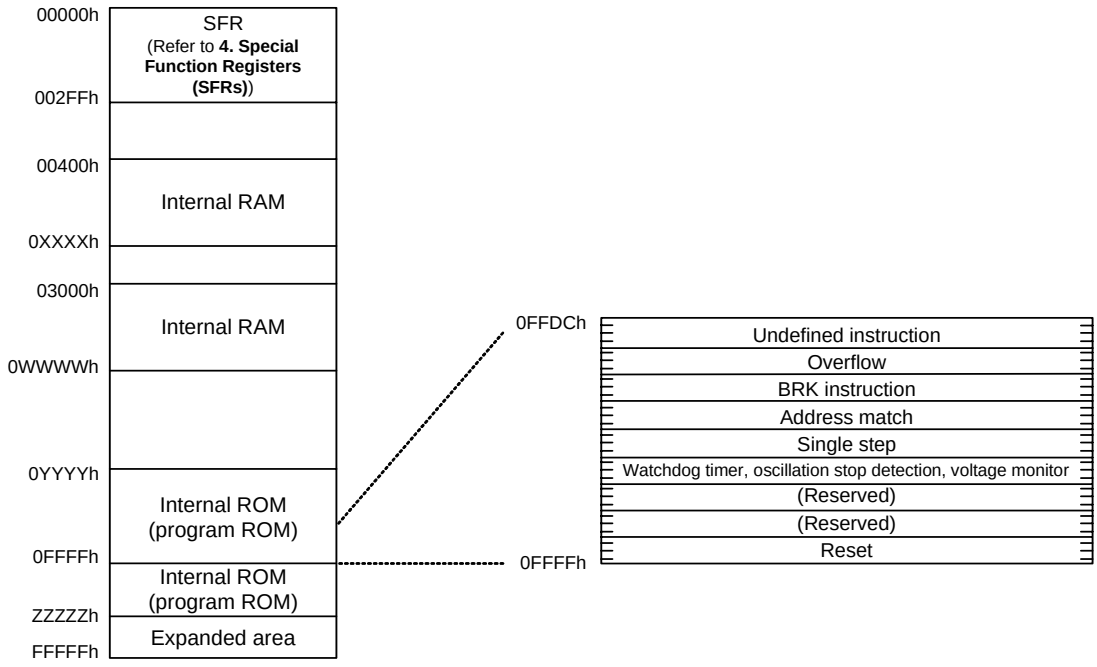
2.8.10 Reserved Bit

If necessary, set to 0. When read, the content is undefined.

3. Memory

3.1 R8C/2A Group

Figure 3.1 is a Memory Map of R8C/2A Group. The R8C/2A group has 1 Mbyte of address space from addresses 00000h to FFFFFh.
The internal ROM is allocated lower addresses, beginning with address 0FFFFh. For example, a 48-Kbyte internal ROM area is allocated addresses 04000h to 0FFFFh.
The fixed interrupt vector table is allocated addresses 0FFDCh to 0FFFFh. They store the starting address of each interrupt routine.
The internal RAM is allocated higher addresses, beginning with address 00400h. For example, a 2.5-Kbyte internal RAM area is allocated addresses 00400h to 00DFFh. The internal RAM is used not only for storing data but also for calling subroutines and as stacks when interrupt requests are acknowledged.
Special function registers (SFRs) are allocated addresses 00000h to 002FFh. The peripheral function control registers are allocated here. All addresses within the SFR, which have nothing allocated are reserved for future use and cannot be accessed by users.



NOTE:
1. The blank regions are reserved. Do not access locations in these regions.

Internal ROM			Internal RAM		
Size	Address 0YYYYh	Address ZZZZZh	Size	Address 0XXXXh	Address 0WWWWh
48 Kbytes	04000h	–	2.5 Kbytes	00DFFh	–
64 Kbytes	04000h	13FFFh	3 Kbytes	00FFFh	–
96 Kbytes	04000h	1BFFFh	7 Kbytes	011FFh	03DFFh
128 Kbytes	04000h	23FFFh	7.5 Kbytes	011FFh	03FFFh

Figure 3.1 Memory Map of R8C/2A Group

Table 4.2 SFR Information (2)[1]

Address	Register	Symbol	After reset
0040h			
0041h			
0042h			
0043h			
0044h			
0045h			
0046h			
0047h	Timer RC Interrupt Control Register	TRCIC	XXXXX000b
0048h	Timer RD0 Interrupt Control Register	TRD0IC	XXXXX000b
0049h	Timer RD1 Interrupt Control Register	TRD1IC	XXXXX000b
004Ah	Timer RE Interrupt Control Register	TREIC	XXXXX000b
004Bh	UART2 Transmit Interrupt Control Register	S2TIC	XXXXX000b
004Ch	UART2 Receive Interrupt Control Register	S2RIC	XXXXX000b
004Dh	Key Input Interrupt Control Register	KUPIC	XXXXX000b
004Eh			
004Fh	SSU/IIC Interrupt Control Register[2]	SSUIC / IICIC	XXXXX000b
0050h	Compare 1 Interrupt Control Register	CMP1IC	XXXXX000b
0051h	UART0 Transmit Interrupt Control Register	S0TIC	XXXXX000b
0052h	UART0 Receive Interrupt Control Register	S0RIC	XXXXX000b
0053h	UART1 Transmit Interrupt Control Register	S1TIC	XXXXX000b
0054h	UART1 Receive Interrupt Control Register	S1RIC	XXXXX000b
0055h	INT2 Interrupt Control Register	INT2IC	XX00X000b
0056h	Timer RA Interrupt Control Register	TRAIC	XXXXX000b
0057h			
0058h	Timer RB Interrupt Control Register	TRBIC	XXXXX000b
0059h	INT1 Interrupt Control Register	INT1IC	XX00X000b
005Ah	INT3 Interrupt Control Register	INT3IC	XX00X000b
005Bh	Timer RF Interrupt Control Register	TRFIC	XXXXX000b
005Ch	Compare 0 Interrupt Control Register	CMP0IC	XXXXX000b
005Dh	INT0 Interrupt Control Register	INT0IC	XX00X000b
005Eh	A/D Conversion Interrupt Control Register	ADIC	XXXXX000b
005Fh	Capture Interrupt Control Register	CAPIC	XXXXX000b
0060h			
0061h			
0062h			
0063h			
0064h			
0065h			
0066h			
0067h			
0068h			
0069h			
006Ah			
006Bh			
006Ch			
006Dh			
006Eh			
006Fh			
0070h			
0071h			
0072h			
0073h			
0074h			
0075h			
0076h			
0077h			
0078h			
0079h			
007Ah			
007Bh			
007Ch			
007Dh			
007Eh			
007Fh			

X: Undefined
NOTES:
1. The blank regions are reserved. Do not access locations in these regions.
2. Selected by the IICSEL bit in the PMR register.

Table 4.6 SFR Information (6)(1)

Address	Register	Symbol	After reset
0140h	Timer RD Control Register 0	TRDCR0	00h
0141h	Timer RD I/O Control Register A0	TRDIORA0	10001000b
0142h	Timer RD I/O Control Register C0	TRDIORC0	10001000b
0143h	Timer RD Status Register 0	TRDSR0	11000000b
0144h	Timer RD Interrupt Enable Register 0	TRDIER0	11100000b
0145h	Timer RD PWM Mode Output Level Control Register 0	TRDPOCR0	11111000b
0146h	Timer RD Counter 0	TRD0	00h
0147h			00h
0148h	Timer RD General Register A0	TRDGRA0	FFh
0149h			FFh
014Ah	Timer RD General Register B0	TRDGRB0	FFh
014Bh			FFh
014Ch	Timer RD General Register C0	TRDGRC0	FFh
014Dh			FFh
014Eh	Timer RD General Register D0	TRDGRD0	FFh
014Fh			FFh
0150h	Timer RD Control Register 1	TRDCR1	00h
0151h	Timer RD I/O Control Register A1	TRDIORA1	10001000b
0152h	Timer RD I/O Control Register C1	TRDIORC1	10001000b
0153h	Timer RD Status Register 1	TRDSR1	11000000b
0154h	Timer RD Interrupt Enable Register 1	TRDIER1	11100000b
0155h	Timer RD PWM Mode Output Level Control Register 1	TRDPOCR1	11111000b
0156h	Timer RD Counter 1	TRD1	00h
0157h			00h
0158h	Timer RD General Register A1	TRDGRA1	FFh
0159h			FFh
015Ah	Timer RD General Register B1	TRDGRB1	FFh
015Bh			FFh
015Ch	Timer RD General Register C1	TRDGRC1	FFh
015Dh			FFh
015Eh	Timer RD General Register D1	TRDGRD1	FFh
015Fh			FFh
0160h	UART2 Transmit/Receive Mode Register	U2MR	00h
0161h	UART2 Bit Rate Register	U2BRG	XXh
0162h	UART2 Transmit Buffer Register	U2TB	XXh
0163h			XXh
0164h	UART2 Transmit/Receive Control Register 0	U2C0	00001000b
0165h	UART2 Transmit/Receive Control Register 1	U2C1	00000010b
0166h	UART2 Receive Buffer Register	U2RB	XXh
0167h			XXh
0168h			
0169h			
016Ah			
016Bh			
016Ch			
016Dh			
016Eh			
016Fh			
0170h			
0171h			
0172h			
0173h			
0174h			
0175h			
0176h			
0177h			
0178h			
0179h			
017Ah			
017Bh			
017Ch			
017Dh			
017Eh			
017Fh			

X: Undefined
NOTE:
1. The blank regions are reserved. Do not access locations in these regions.

Table 4.9 SFR Information (9)[1]

Address	Register	Symbol	After reset
0200h			
0201h			
0202h			
0203h			
0204h			
0205h			
0206h			
0207h			
0208h			
0209h			
020Ah			
020Bh			
020Ch			
020Dh			
020Eh			
020Fh			
0210h			
0211h			
0212h			
0213h			
0214h			
0215h			
0216h			
0217h			
0218h			
0219h			
021Ah			
021Bh			
021Ch			
021Dh			
021Eh			
021Fh			
0220h			
0221h			
0222h			
0223h			
0224h			
0225h			
0226h			
0227h			
0228h			
0229h			
022Ah			
022Bh			
022Ch			
022Dh			
022Eh			
022Fh			
0230h			
0231h			
0232h			
0233h			
0234h			
0235h			
0236h			
0237h			
0238h			
0239h			
023Ah			
023Bh			
023Ch			
023Dh			
023Eh			
023Fh			

NOTE:
1. The blank regions are reserved. Do not access locations in these regions.

Table 4.12 SFR Information (12)(1)

Address	Register	Symbol	After reset
02C0h	A/D Register 0	AD0	XXh
02C1h			XXh
02C2h			
02C3h			
02C4h			
02C5h			
02C6h			
02C7h			
02C8h			
02C9h			
02CAh			
02CBh			
02CCh			
02CDh			
02CEh			
02CFh			
02D0h			
02D1h			
02D2h			
02D3h			
02D4h	A/D Control Register 2	ADCON2	00001000b
02D5h			
02D6h	A/D Control Register 0	ADCON0	00000011b
02D7h	A/D Control Register 1	ADCON1	00h
02D8h			
02D9h			
02DAh			
02DBh			
02DCh			
02DDh			
02DEh			
02DFh			
02E0h			
02E1h			
02E2h			
02E3h			
02E4h	Port P8 Direction Register	PD8	00h
02E5h			
02E6h	Port P8 Register	P8	XXh
02E7h			
02E8h			
02E9h			
02EAh			
02EBh			
02ECh			
02EDh			
02EEh			
02EFh			
02F0h			
02F1h			
02F2h			
02F3h			
02F4h			
02F5h			
02F6h			
02F7h			
02F8h			
02F9h			
02FAh			
02FBh			
02FCh	Pull-Up Control Register 2	PUR2	XXX00000b
02FDh			
02FEh			
02FFh	Timer RF Output Control Register	TRFOUT	00h
FFFFh	Option Function Select Register	OFS	(Note 2)

X: Undefined
NOTES:
1. The blank regions are reserved. Do not access locations in these regions.
2. The OFS register cannot be changed by a program. Use a flash programmer to write to it.

Table 5.5 Flash Memory (Program ROM) Electrical Characteristics

Symbol	Parameter	Conditions	Standard			Unit
			Min.	Typ.	Max.	
–	Program/erase endurance(2)	R8C/2A Group	100(3)	–	–	times
		R8C/2B Group	1,000(3)	–	–	times
–	Byte program time		–	50	400	µs
–	Block erase time		–	0.4	9	s
$t_{d(SR-SUS)}$	Time delay from suspend request until suspend		–	–	97+CPU clock × 6 cycles	µs
–	Interval from erase start/restart until following suspend request		650	–	–	µs
–	Interval from program start/restart until following suspend request		0	–	–	ns
–	Time from suspend until program/erase restart		–	–	3+CPU clock × 4 cycles	µs
–	Program, erase voltage		2.7	–	5.5	V
–	Read voltage		2.2	–	5.5	V
–	Program, erase temperature		0	–	60	°C
–	Data hold time(7)	Ambient temperature = 55°C	20	–	–	year

NOTES:
1. V_{CC} = 2.7 to 5.5 V at T_{opr} = 0 to 60°C, unless otherwise specified.
2. Definition of programming/erasure endurance
   The programming and erasure endurance is defined on a per-block basis.
   If the programming and erasure endurance is n (n = 100 or 10,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.
   However, the same address must not be programmed more than once per erase operation (overwriting prohibited).
3. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).
4. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. It is also advisable to retain data on the erase count of each block and limit the number of erase operations to a certain number.
5. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.
6. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.
7. The data hold time includes time that the power supply is off or the clock is not supplied.

Table 5.6 Flash Memory (Data flash Block A, Block B) Electrical Characteristics(4)

Symbol	Parameter	Conditions	Standard			Unit
			Min.	Typ.	Max.	
–	Program/erase endurance(2)		10,000(3)	–	–	times
–	Byte program time (program/erase endurance ≤ 1,000 times)		–	50	400	µs
–	Byte program time (program/erase endurance > 1,000 times)		–	65	–	µs
–	Block erase time (program/erase endurance ≤ 1,000 times)		–	0.2	9	s
–	Block erase time (program/erase endurance > 1,000 times)		–	0.3	–	s
$t_{d(SR-SUS)}$	Time delay from suspend request until suspend		–	–	97+CPU clock × 6 cycles	µs
–	Interval from erase start/restart until following suspend request		650	–	–	µs
–	Interval from program start/restart until following suspend request		0	–	–	ns
–	Time from suspend until program/erase restart		–	–	3+CPU clock × 4 cycles	µs
–	Program, erase voltage		2.7	–	5.5	V
–	Read voltage		2.2	–	5.5	V
–	Program, erase temperature		-20(8)	–	85	°C
–	Data hold time(9)	Ambient temperature = 55 °C	20	–	–	year

NOTES:
1. V_{CC} = 2.7 to 5.5 V at T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.
2. Definition of programming/erasure endurance
   The programming and erasure endurance is defined on a per-block basis.
   If the programming and erasure endurance is n (n = 100 or 10,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.
   However, the same address must not be programmed more than once per erase operation (overwriting prohibited).
3. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).
4. Standard of block A and block B when program and erase endurance exceeds 1,000 times. Byte program time to 1,000 times is the same as that in program ROM.
5. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. It is also advisable to retain data on the erase count of each block and limit the number of erase operations to a certain number.
6. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.
7. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.
8. -40°C for D version.
9. The data hold time includes time that the power supply is off or the clock is not supplied.

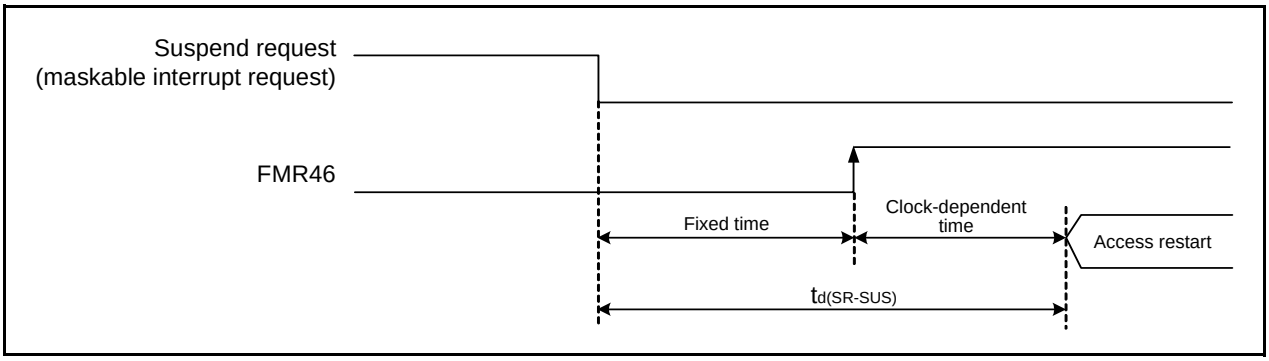


Figure 5.2 Time delay until Suspend

Table 5.7 Voltage Detection 0 Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
V_{det0}	Voltage detection level		2.2	2.3	2.4	V
–	Voltage detection circuit self power consumption	VCA25 = 1, V_{CC} = 5.0 V	–	0.9	–	µA
$t_{d(E-A)}$	Waiting time until voltage detection circuit operation starts(2)		–	–	300	µs
Vccmin	MCU operating voltage minimum value		2.2	–	–	V

NOTES:
1. The measurement condition is V_{CC} = 2.2 V to 5.5 V and T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version).
2. Necessary time until the voltage detection circuit operates when setting to 1 again after setting the VCA25 bit in the VCA2 register to 0.

Table 5.8 Voltage Detection 1 Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
V_{det1}	Voltage detection level		2.70	2.85	3.00	V
–	Voltage monitor 1 interrupt request generation time(2)		–	40	–	µs
–	Voltage detection circuit self power consumption	VCA26 = 1, V_{CC} = 5.0 V	–	0.6	–	µA
$t_{d(E-A)}$	Waiting time until voltage detection circuit operation starts(3)		–	–	100	µs

NOTES:
1. The measurement condition is V_{CC} = 2.2 V to 5.5 V and T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version).
2. Time until the voltage monitor 1 interrupt request is generated after the voltage passes V_{det1}.
3. Necessary time until the voltage detection circuit operates when setting to 1 again after setting the VCA26 bit in the VCA2 register to 0.

Table 5.9 Voltage Detection 2 Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
V_{det2}	Voltage detection level		3.3	3.6	3.9	V
–	Voltage monitor 2 interrupt request generation time(2)		–	40	–	µs
–	Voltage detection circuit self power consumption	VCA27 = 1, V_{CC} = 5.0 V	–	0.6	–	µA
$t_{d(E-A)}$	Waiting time until voltage detection circuit operation starts(3)		–	–	100	µs

NOTES:
1. The measurement condition is V_{CC} = 2.2 V to 5.5 V and T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version).
2. Time until the voltage monitor 2 interrupt request is generated after the voltage passes V_{det2}.
3. Necessary time until the voltage detection circuit operates after setting to 1 again after setting the VCA27 bit in the VCA2 register to 0.

Table 5.11 High-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
fOCO40M	High-speed on-chip oscillator frequency temperature • supply voltage dependence	V_{CC} = 2.7 V to 5.5 V −20°C ≤ T_{opr} ≤ 85°C(2)	39.2	40	40.8	MHz
		V_{CC} = 2.7 V to 5.5 V −40°C ≤ T_{opr} ≤ 85°C(2)	39.0	40	41.0	MHz
		V_{CC} = 2.2 V to 5.5 V −20°C ≤ T_{opr} ≤ 85°C(3)	35.2	40	44.8	MHz
		V_{CC} = 2.2 V to 5.5 V −40°C ≤ T_{opr} ≤ 85°C(3)	34.0	40	46.0	MHz
	High-speed on-chip oscillator frequency when correction value in FRA7 register is written to FRA1 register	V_{CC} = 5.0 V, T_{opr} = 25°C	–	36.864	–	MHz
		V_{CC} = 2.7 V to 5.5 V −20°C ≤ T_{opr} ≤ 85°C	−3%	–	3%	%
–	Value in FRA1 register after reset		08h	–	F7h	–
–	Oscillation frequency adjustment unit of high-speed on-chip oscillator	Adjust FRA1 register (value after reset) to -1	–	+0.3	–	MHz
–	Oscillation stability time	V_{CC} = 5.0 V, T_{opr} = 25°C	–	10	100	µs
–	Self power consumption at oscillation	V_{CC} = 5.0 V, T_{opr} = 25°C	–	550	–	µA

NOTES:
1. V_{CC} = 2.2 to 5.5 V, T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.
2. These standard values show when the FRA1 register value after reset is assumed.
3. These standard values show when the correction value in the FRA6 register is written to the FRA1 register.

Table 5.12 Low-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
fOCO-S	Low-speed on-chip oscillator frequency		30	125	250	kHz
–	Oscillation stability time	V_{CC} = 5.0 V, T_{opr} = 25°C	–	10	100	µs
–	Self power consumption at oscillation	V_{CC} = 5.0 V, T_{opr} = 25°C	–	15	–	µA

NOTE:
1. V_{CC} = 2.2 to 5.5 V, T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.

Table 5.13 Power Supply Circuit Timing Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
$t_{d(P-R)}$	Time for internal power supply stabilization during power-on(2)		1	–	2000	µs
$t_{d(R-S)}$	STOP exit time(3)		–	–	150	µs

NOTES:
1. The measurement condition is V_{CC} = 2.2 to 5.5 V and T_{opr} = 25°C.
2. Waiting time until the internal power supply generation circuit stabilizes during power-on.
3. Time until system clock supply starts after the interrupt is acknowledged to exit stop mode.

Timing Requirements
(Unless Otherwise Specified: Vcc = 5 V, Vss = 0 V at Topr = 25°C) [Vcc = 5 V]

Table 5.18 XIN Input, XCIN Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(XIN)}$	XIN input cycle time	50	–	ns
$t_{WH(XIN)}$	XIN input “H” width	25	–	ns
$t_{WL(XIN)}$	XIN input “L” width	25	–	ns
$t_{c(XCIN)}$	XCIN input cycle time	14	–	µs
$t_{WH(XCIN)}$	XCIN input “H” width	7	–	µs
$t_{WL(XCIN)}$	XCIN input “L” width	7	–	µs

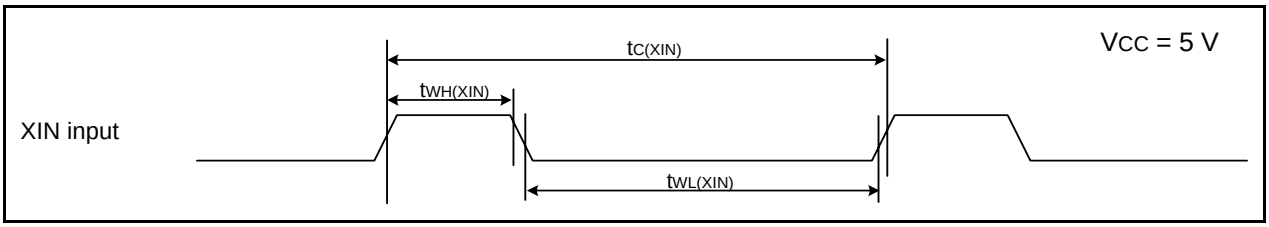


Figure 5.8 XIN Input and XCIN Input Timing Diagram when Vcc = 5 V

Table 5.19 TRAIO Input, $\overline{\text{INT1}}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TRAIO)}$	TRAIO input cycle time	100	–	ns
$t_{WH(TRAIO)}$	TRAIO input “H” width	40	–	ns
$t_{WL(TRAIO)}$	TRAIO input “L” width	40	–	ns

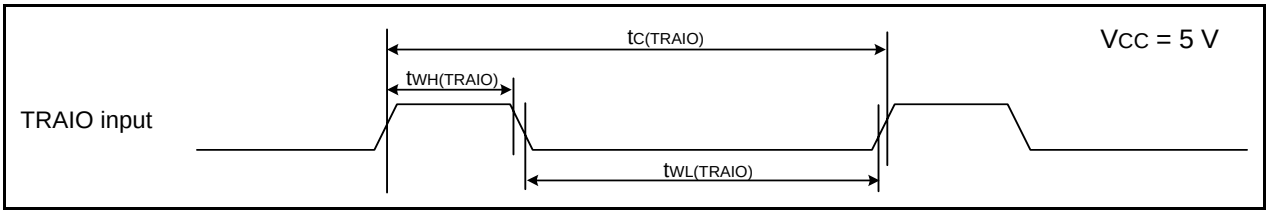


Figure 5.9 TRAIO Input and $\overline{\text{INT1}}$ Input Timing Diagram when Vcc = 5 V

Table 5.20 TRFI Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TRFI)}$	TRFI input cycle time	400(1)	–	ns
$t_{WH(TRFI)}$	TRFI input “H” width	200(2)	–	ns
$t_{WL(TRFI)}$	TRFI input “L” width	200(2)	–	ns

NOTES:
1. When using timer RF input capture mode, adjust the cycle time to (1/timer RF count source frequency × 3) or above.
2. When using timer RF input capture mode, adjust the pulse width to (1/timer RF count source frequency × 1.5) or above.

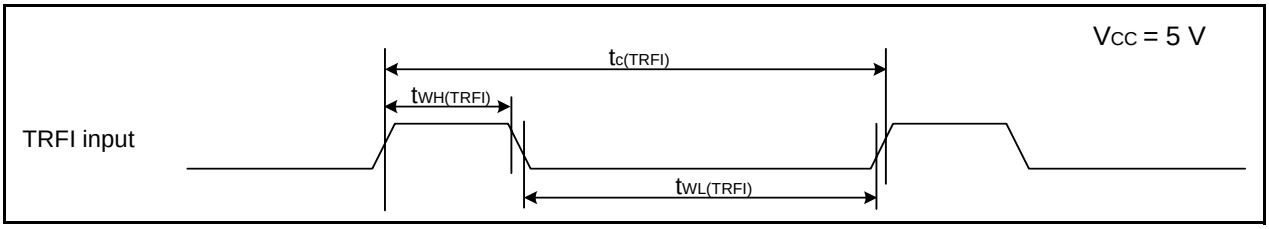


Figure 5.10 TRFI Input Timing Diagram when Vcc = 5 V

Table 5.28 Serial Interface

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CK)}$	CLKi input cycle time	300	–	ns
$t_{W(CKH)}$	CLKi input “H” width	150	–	ns
$t_{W(CKL)}$	CLKi Input “L” width	150	–	ns
$t_{d(C-Q)}$	TXDi output delay time	–	80	ns
$t_{h(C-Q)}$	TXDi hold time	0	–	ns
$t_{su(D-C)}$	RXDi input setup time	70	–	ns
$t_{h(C-D)}$	RXDi input hold time	90	–	ns

i = 0 to 2

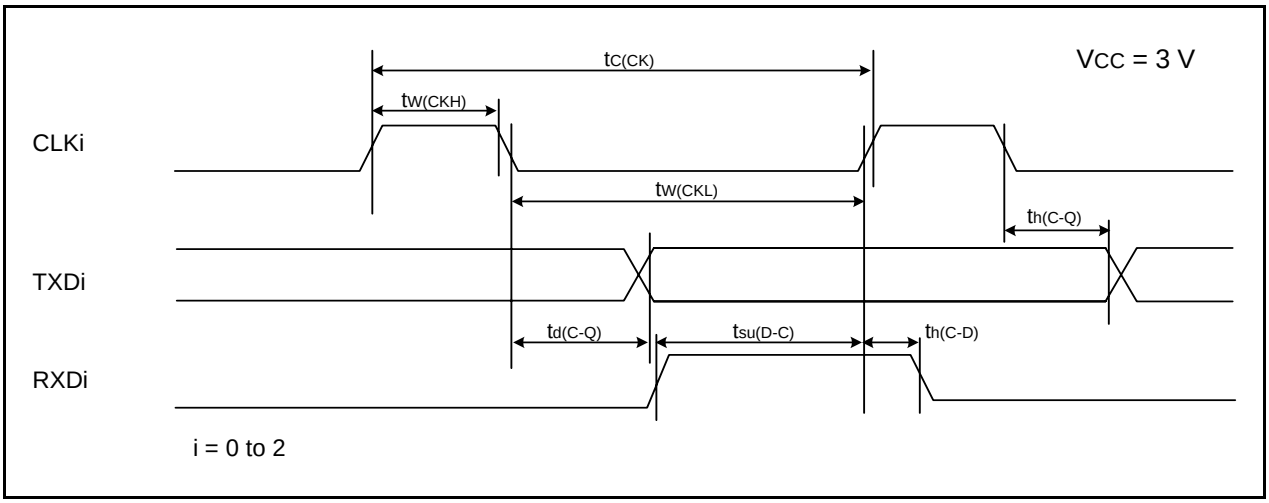


Figure 5.16 Serial Interface Timing Diagram when VCC = 3 V

Table 5.29 External Interrupt $\overline{INTi}$ (i = 0, 2, 3) Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{W(INH)}$	$\overline{INT0}$ input “H” width	380(1)	–	ns
$t_{W(INL)}$	$\overline{INT0}$ input “L” width	380(2)	–	ns

NOTES:
1. When selecting the digital filter by the $\overline{INTi}$ input filter select bit, use an $\overline{INTi}$ input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.
2. When selecting the digital filter by the $\overline{INTi}$ input filter select bit, use an $\overline{INTi}$ input LOW width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

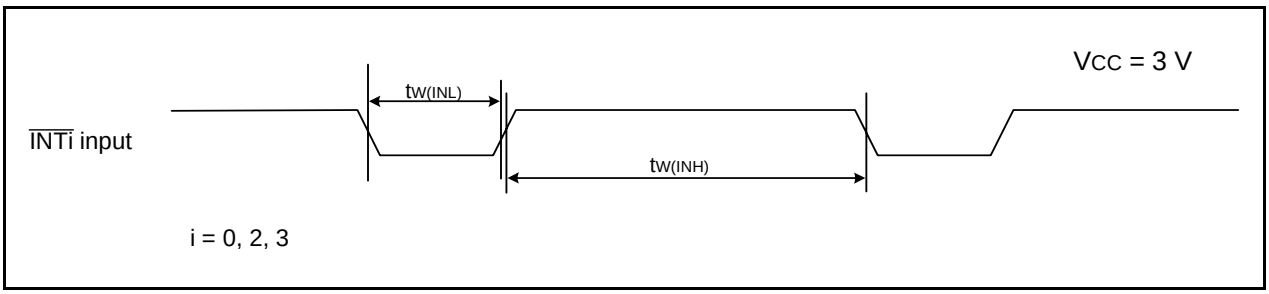


Figure 5.17 External Interrupt $\overline{INTi}$ Input Timing Diagram when VCC = 3 V

Timing requirements
(Unless Otherwise Specified: Vcc = 2.2 V, Vss = 0 V at Topr = 25°C) [Vcc = 2.2 V]

Table 5.32 XIN Input, XCIN Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(XIN)}$	XIN input cycle time	200	–	ns
$t_{WH(XIN)}$	XIN input “H” width	90	–	ns
$t_{WL(XIN)}$	XIN input “L” width	90	–	ns
$t_{c(XCIN)}$	XCIN input cycle time	14	–	µs
$t_{WH(XCIN)}$	XCIN input “H” width	7	–	µs
$t_{WL(XCIN)}$	XCIN input “L” width	7	–	µs

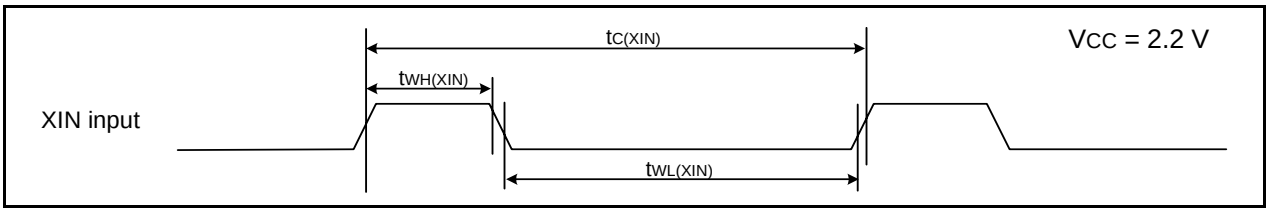


Figure 5.18 XIN Input and XCIN Input Timing Diagram when Vcc = 2.2 V

Table 5.33 TRAIO Input, $\overline{\text{INT1}}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TRAIO)}$	TRAIO input cycle time	TBD	–	ns
$t_{WH(TRAIO)}$	TRAIO input “H” width	TBD	–	ns
$t_{WL(TRAIO)}$	TRAIO input “L” width	TBD	–	ns

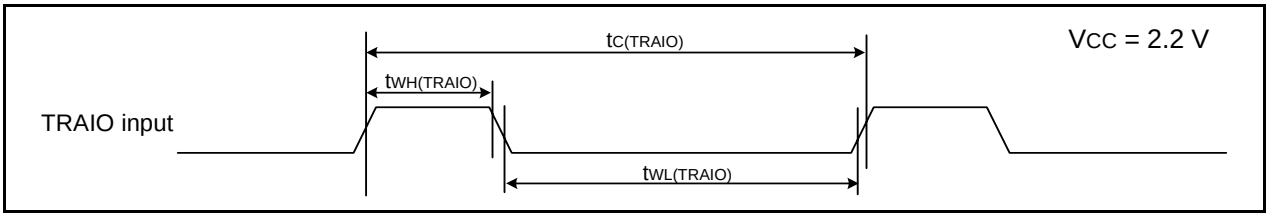


Figure 5.19 TRAIO Input and $\overline{\text{INT1}}$ Input Timing Diagram when Vcc = 2.2 V

Table 5.34 TRFI Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TRFI)}$	TRFI input cycle time	2000(1)	–	ns
$t_{WH(TRFI)}$	TRFI input “H” width	1000(2)	–	ns
$t_{WL(TRFI)}$	TRFI input “L” width	1000(2)	–	ns

NOTES:
1. When using timer RF input capture mode, adjust the cycle time to (1/timer RF count source frequency × 3) or above.
2. When using timer RF input capture mode, adjust the pulse width to (1/timer RF count source frequency × 1.5) or above.

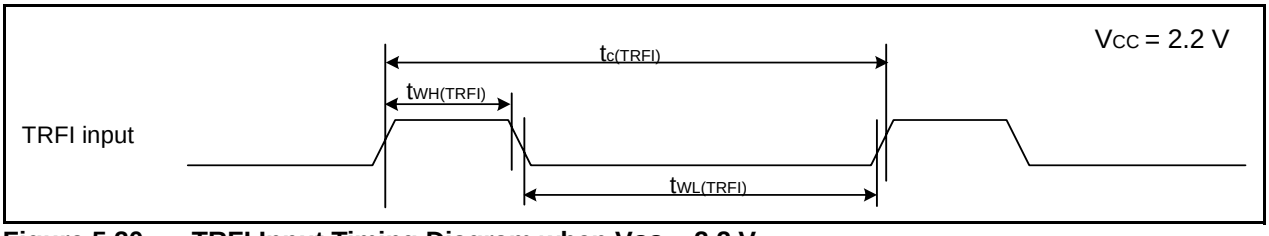


Figure 5.20 TRFI Input Timing Diagram when Vcc = 2.2 V

REVISION HISTORY	R8C/2A Group, R8C/2B Group Datasheet

Rev.	Date	Description	
		Page	Summary
0.01	Apr 03, 2006	–	First Edition issued
0.10	Jun 26, 2006	All pages	Pin name revised CMP0_0 → TRFO00, CMP0_1 → TRFO01, CMP0_2 → TRFO02, CMP1_0 → TRFO10, CMP1_1 → TRFO11, CMP1_2 → TRFO12, TRFIN → TRFI
		2, 4	Table 1.1 Specifications for R8C/2A Group (1) and Table 1.3 Specifications for R8C/2B Group (1); I/O Ports: • Input-only: 3 pins → 2 pins revised Interrupts: • Internal: 17 sources → 23 sources revised
		3, 5	Table 1.2 Specifications for R8C/2A Group (2) and Table 1.4 Specifications for R8C/2B Group (2); ROM Correction Function deleted
		8	Figure 1.3 Block Diagram revised
		9	Figure 1.4 Pin Assignment (Top View) revised
		10, 11	Table 1.7 Pin Name Information by Pin Number (1) and Table 1.8 Pin Name Information by Pin Number (2) revised
		12, 13	Table 1.9 Pin Functions (1) and Table 1.10 Pin Functions (2) revised
		19	Table 4.1 SFR Information (1); • 0008h: Module Standby Control Register, MSTCR, 00h added • 001Ch: “00h” → “00h, 10000000b” revised • NOTE6 added
		20	Table 4.2 SFR Information (2); • 005Fh: Capture Interrupt Control Register, CAPIC, XXXXX000b added
		22	Table 4.4 SFR Information (4); • 00DCh: “00DDh” → “00DCh” revised • 00F5h: “XXXX00XXb” → “00h” revised
		23	Table 4.5 SFR Information (5); • 0105h: LIN Special Function Register, LINCR2, 00h added
		30	Table 4.12 SFR Information (12); • 02C2h, 02C3h: A/D Register 1, AD1, XXh deleted • 02C4h, 02C5h: A/D Register 2, AD2, XXh deleted • 02C6h, 02C7h: A/D Register 3, AD3, XXh deleted
		31	Package Dimensions; “Diagrams showing the latest package dimensions... in the “Packages” section of the Renesas Technology website.” added
0.20	Sep 15, 2006	31 to 54	5. Electrical Characteristics added
0.30	Dec 22, 2006	6	Table 1.5 and Figure 1.1 revised
		7	Table 1.6 and Figure 1.2 revised
		17	Figure 3.1 revised
		18	Figure 3.2 revised

REVISION HISTORY	R8C/2A Group, R8C/2B Group Datasheet

Rev.	Date	Description	
		Page	Summary
0.30	Dec 22, 2006	19	Table 4.1; • 000Ah: "00XXX000b" → "00h" revised • 0008h: "Module Standby Control Register" → "Module Operation Enable Register" revised • 000Fh: "00011111b" → "00X11111b" revised
		37	Table 5.11 revised
1.00	Feb 09, 2007	All pages	"Preliminary" deleted
		3	Table 1.2 revised
		5	Table 1.4 revised
		6	Table 1.5 and Figure 1.1 revised
		7	Table 1.6 and Figure 1.2 revised
		17	Figure 3.1 revised
		18	Figure 3.2 revised
		19	Table 4.1; • 0008h: "Module Standby Control Register" → "Module Operation Enable Register" revised • 000Ah: "00XXX000b" → "00h" revised • 000Fh: "00011111b" → "00X11111b" revised • 002Bh: "High-Speed On-Chip Oscillator Control Register 6" added
		23	Table 4.5; 0105h: "LIN Control Register 2" register name revised
		31	Table 5.2 revised
		32	Table 5.3 and Table 5.4; NOTE1 revised
		37	Table 5.11 revised
		44	Table 5.17 revised
		46	Table 5.21 and Figure 5.11; "i = 0 to 2" revised
		48	Table 5.24 revised
		50	Table 5.28 revised, Figure 5.16 "i = 0 to 2" revised
		52	Table 5.31 revised
		53	Table 5.34 revised
		54	Table 5.35 and Figure 5.21; "i = 0 to 2" revised
2.00	Oct 17, 2007	All pages	"PTLG0064JA-A (64F0G) package" added
		3, 5	Table 1.2 and Table 1.4; • Operating Ambient Temperature: Y version added • Package: 64-pin FLGA added
		6 to 7	Table 1.5 and Figure 1.1 revised
		8	Table 1.6 and Figure 1.2 revised
		10	Figure 1.4 "64-pin LQFP Package" added
		11	Figure 1.5 added
		19 to 20	Figure 3.1 and Figure 3.2 revised
		24	Table 4.4; 00F5h: "00h" → "000000XXb" revised